

# isc N-Channel MOSFET Transistor

2SK3152

#### FEATURES

- Drain-source on-resistance:
  R<sub>DS</sub>(on) ≤ 130mΩ@10V
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

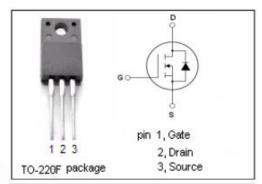
· High fast switching Power Supply

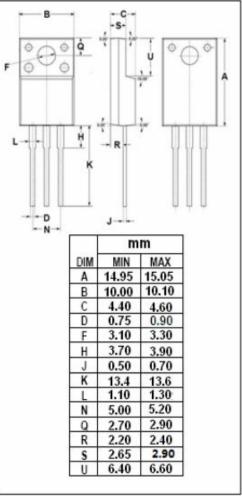
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	120	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous 10		А	
I <sub>DM</sub>	Drain Current-Single Pulsed	40	А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	25	W	
Tj	Max. Operating Junction Temperature 150		$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER MAX		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	5	°C/W	





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 250 μ A	120			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 250 μ A	1		2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =5A			130	- <b>m</b> Ω
		V <sub>GS</sub> =4V; I <sub>D</sub> =5A			170	
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> = 0V			±10	μА
loss	Drain-Source Leakage Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V			10	μА
V <sub>SD</sub>	Diode forward on voltage	I <sub>SD</sub> =10A, V <sub>GS</sub> = 0 V		0.9		V

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